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(71) Applicant (for all designated States except US): SEMI-CONDUCTOR ENERGY LABORATORY CO., LTD.
[JP/JP]; 398, Hase, Atsugi-shi, Kanagawa 2430036 (JP).

(72) Inventors; and

(75) Inventors/Applicants (for US only): NAKASHIMA, Harue [JP/JP]; c/o SEMICONDUCTOR ENERGY LABORATORY CO., LTD., 398, Hase, Atsugi-shi, Kanagawa, 2430036 (JP). NOMURA, Ryoji. ABE, Hiroko. SEO, Satoshi. SAKATA, Junichiro. KUMAKI, Daisuke. IKEDA, Hisao.

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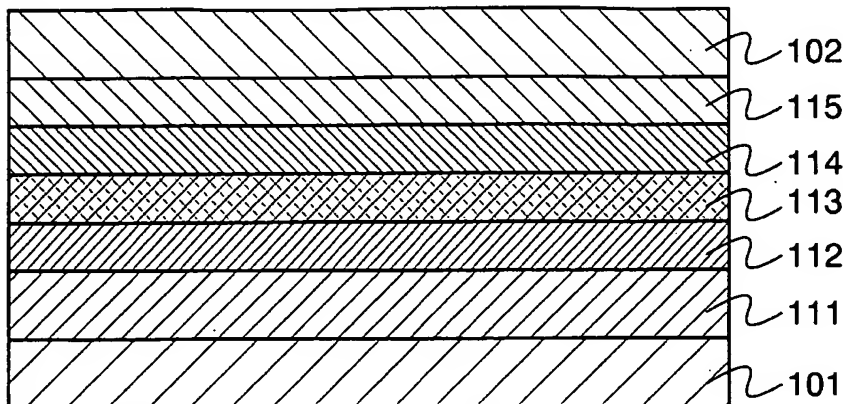
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(54) Title: LIGHT EMITTING ELEMENT, LIGHT EMITTING DEVICE, AND ELECTRONIC DEVICE



(57) Abstract: An object of the present invention is to provide a light emitting element which has low driving voltage and can increase lifetime longer than a conventional light emitting element. One feature is to include a plurality of layers which includes a layer containing a light emitting substance between first and second electrodes, in which at least one layer of the plurality of layers contains a carbazole derivative represented by General Formula (1) and a substance having an electron accepting property with respect to the carbazole derivative represented by General Formula (1). By employing this structure, the above object can be achieved.

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